



12 Bit, Multi-Channel Power & Temp Sensor For Monitor & Control Systems

Features

- Wide Input Supply Range: 4.5V to 40V
- Programmable Gain Differential Amplifier (±10mV, ±25mV, ±50mV, ±250mV Ranges)
- 4 Channel Differential Input Multiplexer (3 Input Channels Plus Ground)
- Integrated 12-bit ADC
- Serial Data Output (SDO) with Data Ready Pin
- Fine Calibration of Full Scale Range (FSR) Using VTRIM Pin
- Bidirectional Current Sense
- Internal Temperature Sensor with 0.2°C Resolution
- Compatible with 3.3V and 5V Microcontrollers
- Operating Temperature Range: -40°C to 85°C
- 5mm x 5mm QFN-28 RoHS Package

Description

The MX844 is a fully integrated subsystem that measures temperature plus differential current and voltage. An internal temperature sensor measures ambient temperature with 2.5°C accuracy. Current and voltage measurements are made differentially through a four-input multiplexer connected to a programmable gain, fully differential sense amplifier. The differential sense amplifier is optimized to measure very small positive or negative voltages near ground for low-side bidirectional sensing. A dual-slope ADC converts the temperature sensor or sense amplifier outputs to a 12-bit digital word that includes 3-1/2 digits plus sign. The input multiplexer channel and programmable gain amplifier range may be changed between ADC conversions. An on-chip voltage regulator enables the MX844 to operate over a wide input voltage range of 4.5V to 40V.

Controller interrupt or over-voltage/over-current signals may be generated by a pair of 12-bit digital comparators configured as a window comparator or for simple threshold detection. The serial port supports standard 4-wire synchronous serial data, or asynchronous serial "talk-only" data, and is compatible with most 3.3V and 5V microcontrollers.

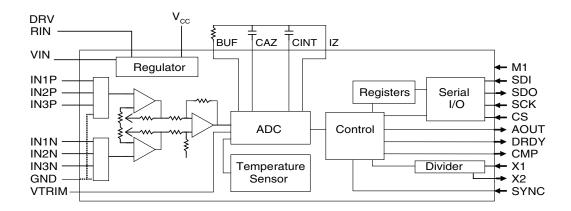




Ordering Information

Part	Description	Quantity
MX844R	QFN-28 Tube	73
MX844RTR	QFN-28 Tape & Reel	2500

Functional Block Diagram





1. Specifications	. 3
1.1 Package Pinout	. 3
1.2 Pin Description	. 3
1.3 Absolute Maximum Ratings	. 4
1.4 DC Electrical Characteristics	
1.5 Thermal Characteristics	
2. Application Operating Mode	. 6
3. Functional Description	. 6
3.1 Voltage Regulator	. 6
3.2 Power-On Reset	
3.3 Oscillator	. 6
3.4 Temperature Sensor	. 6
3.5 Analog/Digital Converter	. 6
3.6 Digital Comparators	. 8
3.7 Asynchronous Output	. 8
3.8 Synchronous Serial I/O	. 9
3.9 Register Address and Bit Assignment	10
3.10 External Serial EEPROM Programming	11
4. Circuit Examples	12
5. Application Example - Power Monitor	13
5.1 Program listing:	
6. Power Monitor Demo Board	20
6.1 Circuit Schematic	20
6.2 Demo Board Layout	
6.3 Demo Board Parts List	22
7. Manufacturing Information	23
7.1 Moisture Sensitivity	
7.2 ESD Sensitivity	23
7.3 Reflow Profile	
7.4 Mechanical Dimensions	24

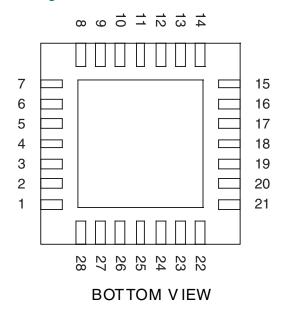
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1 Specifications

1.1 Package Pinout



1.2 Pin Description

Pin#	Name	Description	
1	GND	Ground	
2	VTRIM	Optional Full-Scale Trim Input	
3	BUF	Integrating Resistor Output	
4	IZ	Integrator Zero Output	
5	CAZ	Auto-Zero Capacitor Input	
6	CINT	Integrator Capacitor Input	
7	IN1P	Input Channel 1 Positive	
8	IN1N	Input Channel 1 Negative	
9	IN2P	Input Channel 2 Positive	
10	IN2N	Input Channel 2 Negative	
11	IN3P	Input Channel 3 Positive	
12	IN3N	Input Channel 3 Negative	
13	M1	Divisor Mode Input	
14	SYNC	A/D Converter Reset Input	
15	DRDY	A/D Converter Data Ready Output (Active Low)	
16	SCK	Serial Clock Input	
17	SDO	Serial Data Output	
18	SDI	Serial Data Input	
19	CS	Serial Chip Select (Active Low)	
20	X1	XTAL 1 Input	
21	X2	XTAL 2 Output	
22	AOUT	Asynchronous Data Output	
23	CMP	Comparator Output	
24	V_{CC2}	Must be Connected to V _{CC}	
25	V _{CC}	Regulator Output / Logic Supply Input	
26	VIN	Regulator Voltage Input	
27	RIN	Regulator Internal MOSFET Gate	
28	DRV	Regulator External PNP Base Drive	



1.3 Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Units
VIN, RIN, DRV	-	-	45	V
All Other Pins	-	-	6	٧
Operating Junction Temperature	T_{J}	-	100	°C
Operating Temperature	T _A	-40	85	°C
Storage Temperature	T _{STG}	-55	150	°C

Voltages with respect to GND=0V.

Absolute maximum electrical ratings are at 25°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and affect its reliability.

ESD Warning: ESD (electrostatic discharge) sensitive device. Although the MX844 features proprietary ESD protection circuitry, permanent damage may be sustained if subjected to high energy electrostatic discharges. Proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



1.4 DC Electrical Characteristics

XTAL=8MHz, T_A =25°C, CINT=CAZ=10nF, RINT=68k Ω .

Parameter	Conditions	Min	Тур	Max	Units
V _{CC} Line Regulation	VIN=6V to 45V, No External Load	4.8	-	5.3	V
V _{CC} Load Regulation	VIN=6V, 15mA External Load	4.7	-	-	V
VIN Supply Current	VIN=6V	-	3.2	4.5	mA
Input Bias Current	Selected Input Channel	10	20	40	nA
Input Bias Current Offset	-	-4	-	4	nA
Input Offset Voltage	Differential, Input=0, +/-10mV Scale	-0.4	-	0.4	mV
Input Common Mode	All Input Channels	-300	-	300	mV
ADC Gain Error	+/-250mV Range, at 90% Input	-0.5	-	0.5	
	+/-50mV Range	-1.25	-	0.25	0/
	+/-25mV Range	-1.5	-	0.25	- %
	+/-10mV Range	-1	-	0.25	
ADC Linearity	At Half Full Scale	-3	+/-0.5	3	LSB
ADC Noise	-	-	1.5	-	rms LSB
Temperature Error	-	-2.5	-	2.5	°C
Temperature Slope	-	-	0.2	-	°C/LSB
Temperature Offset	Zero °C	-	3310	-	LSB
Power-On Reset Duration	-	-	100	-	μS
Digital Output Low	I=20mA	-	-	0.5	٧
Digital Output High	I=6mA	V _{CC} -0.5	-	-	٧
Digital Input Low	-	GND	-	0.5	V
Digital Input High	-	2	-	V _{CC}	٧
Digital Input Current	-	-	-	+/- 1	μΑ
Clock Frequency	Terminal X1	0.1	-	20	MHz
Clock Input Low	Terminal X1	GND	-	0.4	V
Clock Input High	Terminal X1	2	-	V _{CC}	V
Clock Input Current	Terminal X1	-	-	50	μА

1.5 Thermal Characteristics

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	-	110	-	°C/W



2 Application Operating Mode

At the end of the power-on reset period, pin CS is sensed to determine the operating mode. Placing an external resistor to $V_{\rm CC}$ on pin CS will cause the MX844 to enter the slave mode. In this mode the synchronous serial I/O port can be connected to a companion microcontroller for full control of the MX844 from the microcontroller.

If a resistor to GND is connected to CS, then the MX844 enters the master mode at power-up and fetches commands from a 93C46 serial EEPROM operating in the 64 by 16 mode. In this mode, the MX844 operates as the master and sends clock, data, and select to the EEPROM and reads back the

3 Functional Description

3.1 Voltage Regulator

There are three methods of powering the MX844.

- 1) An external 4.5 to 5.5V supply is connected to V_{CC} , V_{CC2} , and VIN. Pins DRV and RIN are no-connect or connected together.
- 2) VIN is connected to a 6 to 40V supply. DRV is connected to RIN, thus utilizing the internal pass element.
- 3) VIN is connected to a 6 to 40V supply. An external PNP transistor such as the MMBTA56 or BCX53 is used for the pass element. The PNP transistor's emitter, base, and collector are connected to pins VIN, DRV, V_{CC} respectively. RIN must be connected to VIN.

3.2 Power-On Reset

The MX844 contains a power-on reset circuit that resets all the internal flip-flops and initializes the internal registers to zero. The reset circuit will also generate a reset condition if the voltage at pin V_{CC} drops to approximately 3.8V.

3.3 Oscillator

The oscillator configuration consists of a crystal/resonator connected between pins X1 and X2 and a capacitor to GND on both pins. The capacitor value depends on the crystal/resonator but is usually

EEPROM data. This mode is useful when the MX844 operates as a stand-alone data acquisition system with a fixed pattern of measurement scanning. To facilitate electrically isolated measurements the data can be sent to a computer's serial port using only one wire connected through a single opto-isolator.

If, neither an EEPROM or microcontroller are connected to the MX844, and CS is connected to V_{CC}, operation defaults to that of all zeroes in the control register (ADC clock = input clock / 8, input channel IN1, +/- 50mV range). The asynchronous data output has a valid stream of measurement information.

between 15 and 27pF. Alternatively, an external clock may be input to pin X1, with X2 floating. Nominal DC self-bias at pin X1 is 800mV. In either case the clock is internally AC coupled, therefore clock rates below 100KHz are not recommended.

3.4 Temperature Sensor

The internal temperature sensor is selected for measurement by setting the control register bits for a full scale of +/-250mV and setting the unipolar bit. The temperature value read from the ADC consists of an offset value plus the slope. To convert to a standard temperature scale it is necessary to subtract the constant offset and then multiply by a constant that matches the standard scale desired.

Self-heating of the internal temperature sensor will occur due to the device power dissipation. The maximum heating will occur when the internal pass element is used in conjunction with a high supply voltage.

3.5 Analog/Digital Converter

Selection of the input channel and the full scale range is accomplished by writing 5 bits in the control register. An additional 3 bits in the control register in combination with the M1 pin setup the internal clock dividers. The ADC is a bipolar-input dual slope type with clock period tAD equal to a multiple of the clock period at pin X1 (tClock). The ADC conversion time consists of 1024 * tAD of

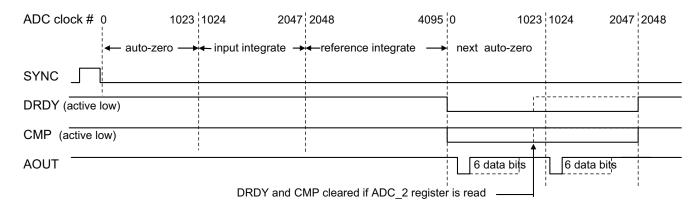


input integration, and 2048 * tAD of reference integration. The result of the analog to digital conversion can be read using the serial I/O port and is also transmitted on pin AOUT in an asynchronous serial format. The DRDY pin transitions low at the end of the reference integration period to indicate that data is stable and may be read through the synchronous serial I/O. The data becomes not valid when DRDY returns high. The status of DRDY is also available in bit 7 of the ADC_1 register.

The SYNC pin is connected to GND to enable free-running ADC conversions. Alternatively, if SYNC

transitions high, the ADC is immediately driven to the start of the auto-zero time. When SYNC is returned to a logic low, the next rising edge at pin X2 will start the ADC timing.

The input channel and full scale range may be changed in between ADC conversions, however it is recommended that such commands be written into the MX844 as soon as possible after pin DRDY transitions low. This allows the maximum settling time prior to the next ADC conversion.



CMP is the digital compare output that is described later. AOUT is the asynchronous serial output of the ADC.

The ADC output code is offset-binary. An example of the coding is shown here for the +/-50mV range and the corresponding unipolar range of 0 to 100mV:

Bipolar Input	Unipolar Input	Binary Output (D11:D0)	Hexadecimal
50mV	100mV	111111111111	FFF
0 + 1/2 LSB	50mV + 1/2 LSB	10000000000	800
0 - 1/2 LSB	50mV - 1/2 LSB	01111111111	7FF
-50mV	0	00000000000	000

Two external components, Rin and Cint, should be chosen such that the value of Cint in pF is 4 to 7 * tAD and the time constant of Rint * Cint is 300 to 450 * tAD. The value of Rint should be between 47K and 220K ohm. For example, for t(AD) = 1.6 uS, a set of suitable values would be 56K ohm and 10nF (RC = 560uS, ratio = 350). The value of the auto-zero capacitor Caz is typically equal to Cint.

VTRIM is either a no-connect pin or can be used to fine-trim the ADC full scale by +/- 1%. The following circuit is recommended if fine trimming is desired:

$$V_{cc}$$
 $20k\Omega$
 $1k\Omega$

GND



3.6 Digital Comparators

Two 12-bit registers form a window comparator of the ADC output data. The value of comparator1 must always be set to a value greater than comparator2. There are three cases to consider, depending on whether the comparator values are above or below 800h:

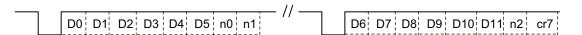
- 1) If the value of comparator1 is greater than 800h and the value of comparator2 is less than 800h, then CMP pulses when the ADC value is greater than or equal to comparator1, or less than or equal to comparator2.
- 2) If the value of comparator1 is greater than 800h and the value of comparator2 is greater than 800h, then CMP pulses when the ADC value is greater than or equal to comparator1, or less than comparator2.
- 3) If the value of comparator1 is less than 800h and the value of comparator2 is less than 800h, then CMP pulses when the ADC value is greater than comparator1, or less than or equal to comparator2.

In all cases, CMP will go logic low at the same time as DRDY transitions low and CMP will return high when the ADC_2 register is read or after 2048 *tAD (see the ADC timing diagram). The status of CMP is also available in bit 6 of the ADC_1 register.

In a typical application CMP would cause a controller interrupt, at which time the controller reads the actual ADC output that caused the interrupt (which clears the DRDY and CMP status bits) and takes appropriate action. Another application would be to connect CMP to over-current or over-voltage shutdown circuitry.

3.7 Asynchronous Output

The ADC result is transmitted on pin AOUT in 8-bit, no parity asynchronous NRZ serial format. Two characters of 8 bits each are transmitted for each ADC conversion, with a start bit just prior to the data (see the figure below).



D[11:0] is the 12-bit result of the ADC conversion. Bit cr7 is the value of the control register bit 7. Bits n2, n1, n0 are automatically inserted which indicate the address of the serial EEPROM. These bits can be used by the receiver to identify which channel and range are being transmitted. The EEPROM address is reset to zero by the SYNC pin pulse. The "ANALOG/DIGITAL CONVERTER" section of this document shows the timing of the asynchronous output bytes relative to the conversion cycle.



Example internal divider settings and clock frequencies for standard baud rates:

CR7:5	M1	Baud Divider	ADC Divider	Clock (MHz)	Baud Rate	ADC Conv/s	Clock (MHz)	Baud Rate	ADC Conv/s
000	1	8x52	8	12	28.8k	366	16	38.4k	488
001	1	4x52	4	6	28.8k	366	8	38.4k	488
010	1	12x64	12	11.059	14.4k	225	14.746	19.2k	300
011	1	13x64	13	12	14.4k	225	16	19.2k	300
000	0	8x64	8	14.746	28.8k	450	9.83	19.2k	300
001	0	4x64	4	14.746	57.6k	900	9.83	38.4k	600
010	0	6x64	6	11.059	28.8k	450	14.746	38.4k	600
011	0	3x64	3	11.059	57.6k	900	7.37	38.4k	600
100	1	8x128	8x4x5	9.83	9600	15			
101	1	9x128	9x4x5	11.059	9600	15			
110	1	12x128	12x4x5 14.746	9600	15				
111	1	13x128	13x4x5 16.0	9600	15				
100	0	8x128	8x4x6	9,83	9600	12.5			
101	0	9x128	9x4x6	11.059	9600	12.5			
110	0	12x128	12x4x6 14.746	9600	12.5				
111	0	13x128	13x4x6 16.0	9600	12.5				

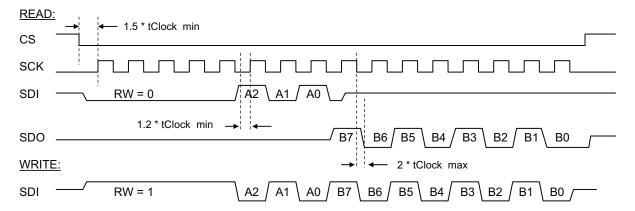
3.8 Synchronous Serial I/O

The MX844 (slave) can communicate with a microcomputer (master) via a three wire plus chip select serial interface. The control register, the two digital comparator values, and the ADC result are accessed by specifying a 3-bit address A[2:0]. Chip

select CS, serial clock SCK, and serial data input SDI are output from the master controller to the MX844. Serial data output SDO is driven by the MX844 when selected by CS = 0. SDO is high impedance when CS = 1. SCK and SDI are don't care when CS = 1.

SERIAL INTERFACE TIMING

tClock = the period of the X1 input clock



SCK minimum high or low time is 3 * tClock.

SDO is high impedance until data read out, and then returns to high impedance due to the rising edge of CS.



3.9 Register Address and Bit Assignment

All registers are read/write except for the two ADC result registers which are read only. The left hand

column refers to the data bits shown as B7 through B0 on the synchronous serial I/O timing diagram.

CONTROL REGISTER, address A[2:0] = 000 binary

		ADC Clo	ck Divisor	Baud Ra	te Divisor
CR[7:5] Clock Divisor	<u>bits</u>	M1 Low	M1 High	M1 Low	M1 High
	000	8	8	512	416
	001	4	4	256	208
	010	6	12	384	768
	011	3	13	192	832
	100	192	160	1024	1024
	101	216	180	1152	1152
	110	288	240	1536	1536
	111	312	260	1664	1664
CR[4:3] Input Channel Select	00	IN1			
	01	IN3			
	10	GND			
	11	IN2			
CR[2:0] Full Scale Select: V(INxP) - V(iNxN)	000	±50mv			
	001	±25mv			
	010	±250mv			
	011	±10mv			
	100	0mV to 100m	ηV		
	101	0mV to 50mV	1		
	110	Selects the Ir	nternal Tempera	ture Sensor	
	111	0mV to 20mV	<i>I</i>		

COMP_1 REGISTER: A[2:0]=001 binary

7:0 Eight Least Significant Bits of Comparator 1

COMP_2 REGISTER: A[2:0]=010 binary

7:0 Eight Least Significant Bits of Comparator 2



COMP_MSN REGISTER: A[2:0]=011 binary

7:4	Four Most Significant Bits of Comparator 1
3:0	Four Most Significant Bits of Comparator 2

ADC_1 REGISTER: A[2:0]=100 binary

7	DRDY Status	0=Data Ready 1= Data Not Ready
6	CMP Status	0=ADC Data Outside Comparator Window 1=ADC Data Inside Comparator Window
5	Reserved	
4	Reserved	
3	ADC Data D11	
2	ADC Data D10	
1	ADC Data D9	
0	ADC Data D8	

ADC_2 REGISTER: A[2:0]=101 binary

7:0	ADC Data D[7:0]	
-----	-----------------	--

3.10 External Serial EEPROM Programming

In this mode the MX844 auto-increments the EEPROM address from 0 up to 7 and then the address rolls back to 0. A single EEPROM word is read at the beginning of every ADC auto-zero period and is interpreted by the MX844 as a synchronous serial I/O write command. These commands control the scanning sequence of the ADC channels, the full scale ranges, and the internal dividers. The MX844 accesses the EEPROM as if it were a ROM and will not write or erase the EEPROM. In the master mode the first data bit serially read out of the EEPROM must always be a logic 1 which indicates a write (of the MX844 register). The second through fourth bits are the address field, followed by eight data bits. The last four bits of the EEPROM word are don't cares.

One 16-bit word of the 93C46 serial EEPROM is used to hold one MX844 synchronous serial I/O instruction. Each pulse of SCK corresponds to one bit in the EEPROM. However, the data is aligned such that the MX844 R/W bit that occurs at the 5th SCK pulse of the serial interface timing is the MSB in the EEPROM word. The last 4 bits of the EEPROM word are always zero. For example, the instruction to write the byte 1Ah into the MX844 control register (IN2 +/-250mV scale) would be programmed into the EEPROM as the 16-bit quantity 81A0h. Entered into a typical programmer file editor in the least-significant-byte first format it would be the byte A0h followed by the byte 81h. Eight pairs of bytes can be specified in the programming file (EEPROM address 0 to 7). The MX844 will ignore the remaining contents of the EEPROM (address > 7).



4 Circuit Examples

The two examples shown below are for illustration only, and are not complete schematics. The power dissipation will determine if the external pass element

is required regardless of whether an eeprom or a microcontroller are connected.

Figure 1. MX844 Internal Pass Element: Serial EEPROM Connection

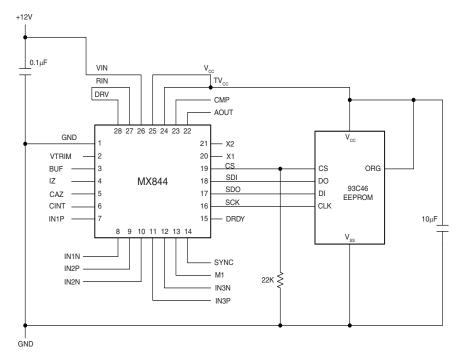
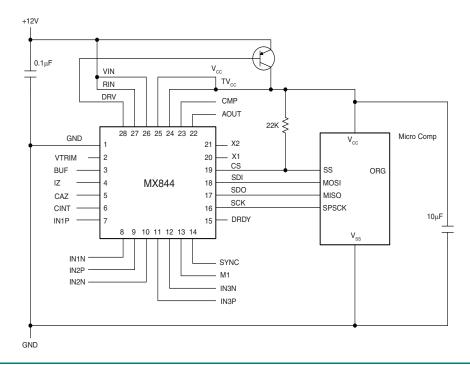


Figure 2. MX844 External Pass Element: Microcontroller Connection





5 Application Example - Power Monitor

This design example illustrates the application of the MX844 as an AC line power monitor.

In this design the MX844 operates as a serial bus master, reading instructions from an external serial EEPROM.

Following application of power, the first 16-bit word read from the EEPROM is 0x8200 (using "C" notation to indicate a hexadecimal number) which in conjunction with the connection of terminal M1 to V_{CC} , causes the MX844 to set it's internal dividers for 488 A/D samples per second and an asynchronous baud rate of 38.4 Kbaud when using an 8 MHz clock. The first measurement is made from input channel IN1 on the +/- 50 mV scale. For the power meter this is a measurement of the AC line current flowing through

00	82	00	83	00	82	A0	83	00	82	A0	83	00	82	A0	83
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00

Note that the 16-bit word is broken up into two bytes with the least significant byte first.

The power monitor is powered directly off the line using resistors R14 - R20, diodes D1 and D2, and capacitor C1 to produce an unregulated DC voltage for the MX844.

Opto-isolator U3 provides isolation between the AC power line and the computer serial port. Dual transistors Q1 and Q2 and related circuitry amplify the photodiode signal into the required RS-232 signal for the computer serial port. Power for the photodiode amplifier is very small and is supplied by the serial port DTR and RTS terminals.

By analyzing the data stream from the MX844 the computer software program can determine the RMS line voltage, the RMS line current, the RMS power consumed, and the power factor of the load.

Each digitized sample is transmitted to the computer as two 8-bit "characters" in asynchronous RS-232

sense resistor R1. A value of 0.002 Ohm for R1 results in a +/- 25A current scale.

The second instruction is 0x83A0, which results in a measurement from input channel IN2 on the +/- 250 mV scale. For the power meter this is a measurement of the AC line voltage through the voltage attenuator consisting of resistors R2, R3, and R4 which provide a full scale of +/- 407 V.

The MX844 cycles through the first eight addresses of the EEPROM. Therefore the first two instruction codes are repeated three more times in order to continuously alternate between AC line voltage and current measurements.

This is how the EEPROM contents would appear in a typical programmer buffer editor:

format. Embedded in the two characters are the 12 bits of data and a 3-bit EEPROM address.

The software performs the following tasks:

- a. Synchronize to the EEPROM address.
- b. Acquire 256 samples.
- Separate into 128 voltage readings and 128 current readings.
- d. Calculate the RMS value of the voltage and the current (standard deviation of the 128 data set).
 Apparent power is Vrms * Irms.
- e. Perform "flat top" windowing and then FFT on the voltage to determine the whether the frequency is 60Hz or 50Hz. The FFT also gives an RMS amplitude value for the voltage.
- f. Determine the voltage at the time of the current measurements by sine wave interpolation between each pair of voltage readings.
- g. Calculate the real power using the 128 measured current values and the 128 interpolated voltage values. Also calculate the power factor.



5.1 Program listing:

```
/* This program reads alternating samples of voltage and current from */
/* the MX844 AOUT terminal which is connected to a PC com1 port with */
/* the demo board circuitry. */
/* This demo program directly accesses the PC's 16550 UART using inp() */
^{\prime \star} and outp() functions and therefore must be compiled and run in ^{\star \prime}
/* real mode (DOS box) under win98. */
#include <stdio.h>
#include <conio.h>
#include <math.h>
void frier(double *, double *, int);
int round (double);
#define NMAX 256
double xd[NMAX+2];
double yd[NMAX+2];
double pd[NMAX+2];
FILE *inf;
int lost, m, onez, twoz, rdata, i, j, w, d[4*NMAX];
int ad[NMAX], ad2[NMAX], n[NMAX], n2[NMAX];
long t;
int np, imax;
double rt2, ln10, min, max, fmax, k, pi, nbw, resHz, samHz;
double wt, b, a, vrms, irms, pf, rp, cv;
double ivsum, sum, ss, sumi, ssi, aw, av;
float vscale, iscale;
main(argc, argv)
int argc;
char *argv[];
  rt2 = sqrt(2);
  ln10 = log(10);
  pi = 4 * atan(1);
  np = 128; /* number of points in FFT time series */
  /st use the following line for 12MHz clock with a divider of 8
  or 6MHz clock with a divider of 4 */
  /* samHz = 12e6/8/4096/2;*/
  /* use the following line for 8MHz clock with a divider of 4 */
  samHz = 8e6/4/4096/2;
  vscale = (0.250 / 2048) * 1629 ; /* 440 K & 270 resistor divider */
  iscale = (0.050 / 2048) / 0.002; /* 0.002 ohm shunt */
  /* setup the com1 port */
  outp(0x3fb, 0x83); /* 8 bits no parity, DLAB=1 */
  outp(0x3f9,0); /* upper divisor = 0 */
  /*outp(0x3f8,4);*//*lower divisor = 4 (28800 baud) */
  outp(0x3f8,3); /* lower divisor = 3 (38400 baud) */
  outp(0x3fc,1); /* DTR +V, RTS -V */
  outp(0x3fb,3); /* DLAB = 0 */
  /* open the output log file */
  inf = fopen("meter.log", "w");
  /* initialize arrays */
  for(i=0;i<np;i++)
     {
```



```
ad[i] = 0;
     ad2[i] = 0;
     n[i] = 0;
     n2[i] = 0;
  }
for (i=0; i<4*np; i++) d[i] = 0;
/* start data acquisition from MX844 */
lost = 1;
while(lost == 1)
  {
     /* synchronize to MX844 async data stream */
     /* find n0, n1 = 00 and n2, \bar{n}3 = 00 */
     twoz = 0;
     while (twoz == 0)
       onez = 0;
       /* read bytes until n0, n1 = 00 */
       while (onez == 0)
          while ((inp(0x3fd) \& 1) == 0) \{w=1;\} /*wait for data ready*/
          d[0] = inp(0x3f8);
          if((d[0] \& 0x00c0) == 0) onez = 1;
       /* read the next byte */
       w = 0;
       while ((inp(0x3fd) & 1) == 0) \{w=1;\} /* wait for data ready */
       d[1] = inp(0x3f8);
       if((d[1] & 0x00c0) == 0) twoz = 1;
       else /* change "phase" */
          w = 0;
          while ((inp(0x3fd) \& 1) == 0) \{w=1;\} /*wait for data ready*/
          d[0] = inp(0x3f8);
  } /* end twoz */
m=0;
/* read the actual data */
for(i=2;i<4*np;i++)
  {
     w = 0;
     while ((inp(0x3fd) \& 1) == 0) \{w=1;\} /*wait for data ready */
     d[i] = inp(0x3f8);
     if (w==0) m++;
     /* printf("\n%02X %1d",d[i],w); */
  }
/* check for loss of sync in the data */
lost = 0;
for(i=0;i<np;i++)
  {
     m = ((0xc0 \& d[2*i]) >> 6) + ((0xc0 \& d[2*i+1]) >> 4);
     if(m != i % 8) lost = 1;
  if (lost == 1)
       printf("lost sync\n");
       for(t=0;t<200000;t++); /* wait to try again */
} /* done with acquisition */
```



```
/* separate voltage and current, report data */
for(i=0;i<np;i++)
  {
    ad[i] = (0x3f \& d[4*i]) + (64*(0x3f \& d[4*i+1]));
    ad2[i] = (0x3f & d[4*i+2])+(64*(0x3f & d[4*i+3]));
    n[i] = ((0xc0 \& d[4*i]) >> 6) + ((0xc0 \& d[4*i+1]) >> 4);
    n2[i] = ((0xc0 \& d[4*i+2])>>6)+((0xc0 \& d[4*i+3])>>4);
  }
/* report voltage readings */
for(i=0;i<np;i++)
     fprintf(inf,"(%1d)%4d ",n[i],ad[i]);
    if(i%8 == 7) fprintf(inf,"\n");
fprintf(inf,"\n");
/* report current readings */
fprintf(inf, "Current:\n");
for(i=0;i<np;i++)
     fprintf(inf,"(%1d)%4d ",n2[i],ad2[i]);
    if (i%8 == 7) fprintf(inf,"\n");
  }
/* calculate Vrms */
sum = 0;
ss = 0;
for(i=0;i<np;i++)
  {
    sum += ad[i];
    ss += (double)ad[i] * (double)ad[i];
  }
vrms = sqrt(ss/np - (sum/np) * (sum/np));
fprintf(inf,"\n%8.1f Volts rms\n", vrms * vscale);
printf("\n%8.1f Volts rms\n", vrms * vscale);
/* calculate Irms */
sumi = 0;
ssi = 0;
for(i=0;i<np;i++)
  {
    sumi += ad2[i];
    ssi += (double)ad2[i] * (double)ad2[i];
  }
irms = sqrt(ssi/np - (sumi/np) * (sumi/np));
fprintf(inf,"%8.2f Amps rms\n",irms * iscale);
printf("%8.2f Amps rms\n",irms * iscale);
/* calculate apparent power (VA) */
aw = vrms * vscale * irms * iscale;
printf("%8.1f VA\n",aw);
fprintf(inf,"%8.1f VA\n",aw);
fprintf(inf,"%5.1f calculated average V counts\n", sum/np);
fprintf(inf,"%5.1f calculated average I counts\n", sumi/np);
av = sum/np;
/* fill the FFT data arrays */
for(i=1;i<=np;i++) /* fft data [1..np] instead of [0..np-1] */
```



```
{
     xd[i] = ad[i-1];
     yd[i] = 0;
xd[0] = 0; yd[0] = 0;
xd[np+1] = 0; yd[np+1] = 0;
/* perform the windowing */
k = 2 * pi / (np - 1); /* i*k==0 if i=0, ==2*pi if i=127 */
for(i=0;i<np;i++)</pre>
  { /* remember [1..np] */
     xd[i+1] *= 1-1.8533*cos(i*k)+0.7046*cos(2*i*k);
resHz = samHz / np; /* frequency resolution */
nbw = 3.44 * resHz; /* calculate noise bandwidth */
frier(xd, yd, round(log(np)/log(2)));
/* report the FFT result */
max = 0;
for (i=1; i \le 1+np/2; i++)
  {
     pd[i] = rt2 * sqrt(pow(xd[i],2) + pow(yd[i],2));
     fprintf(inf, "%8.2f %12.4f", resHz*(i-1), pd[i]);
     fprintf(inf," %12.4f %12.4f\n",xd[i],yd[i]);
     if((pd[i] > max) \&\& i>9)
          max = pd[i];
          imax = i;
          fmax = resHz*(i-1);
if (pd[imax+1]/pd[imax] > 0.8) fmax += resHz/2;
if (pd[imax-1]/pd[imax] > 0.8) fmax -= resHz/2;
fmax = (double) round(fmax);
fprintf(inf,"%5.1f Vrms from FFT at %2.0f Hz\n", max*vscale, fmax);
/* interpolate V at time of I and calculate real power */
fprintf(inf,"Instantaneous VA:\n");
ivsum = 0;
for(i=0;i<np-1;i++)
     b = (double) ad[i] - av;
     wt = 2*pi*fmax/samHz;
     a = ((double)ad[i+1]-av-b*cos(wt))/sin(wt);
     wt = 2*pi*fmax*0.5/samHz;
     cv = a*sin(wt) + b*cos(wt);
     rp = -(iscale*(ad2[i] - av)*vscale*cv);
     fprintf(inf,"%7.2f ",rp);
if(i%8 == 7) fprintf(inf,"\n");
     ivsum += rp;
  }
/* the last data point is special */
wt = 2*pi*fmax*1.5/samHz;
cv = a*sin(wt) + b*cos(wt);
rp = -(iscale*(ad2[np-1] - av)*vscale*cv);
fprintf(inf,"%7.2f ",rp);
if(i%8 == 7) fprintf(inf,"\n");
ivsum += rp;
/* report the results */
fprintf(inf,"\n");
```



```
if(ivsum < 0) ivsum = -ivsum;</pre>
  printf("%8.1f real wattsn",ivsum/np);
  fprintf(inf,"%8.1f real watts\n",ivsum/np);
  pf = (ivsum/np) / aw;
  if (pf>1) pf=1;
  printf("%8.2f power factor\n",pf);
  fprintf(inf,"%8.2f power factor\n",pf);
  fclose(inf);
} /* end main */
/* rounding function */
int round(double x)
  if(x>0)
     return((int) (x + 0.5));
     else
     return((int) (x - 0.5));
/* FFT routine */
void frier(double *x, double *y, int ig)
/* ig = number of points as a power of 2 */
/* for example, ig = 8 for 256 point FFT */
  double p, y1, y2, y3, y4;
  int n, m, m1, m2, k, k1, k2, k3, k4, k5, i, j, l, ig1;
  n = 1 << iq;
  p = 8 * atan(1) / n;
  for (i=1; i<=n; i++)
     {
        *(x+i) /= n;
       *(y+i) /= n;
  for (l=1; l<=iq; l++)
     {
       ig1 = 1 << (ig-1);
       m = 0;
       k4 = 1 \ll (1-1);
       for(i=1;i<=k4;i++)
             k1 = m / ig1;
             k2 = 0;
             k3 = 1 << (ig-1);
             for(k=1; k<=ig; k++)
               {
                  if((1 \& k1) == 1) k2 += k3;
                  k3 >>= 1;
                  k1 >>= 1;
             y1 = cos(p*k2);
             y2 = -\sin(p*k2);
             for (k=1; k \le ig1; k++)
               {
                  m1 = m + ig1 + 1;
                  m2 = m + 1;
                  y3 = *(x+m1) * y1 - *(y+m1) * y2;
                  y4 = *(x+m1) * y2 + *(y+m1) * y1;
                  *(x+m1) = *(x+m2) - y3;
                  *(y+m1) = *(y+m2) - y4;
                  *(x+m2) += y3;
                  *(y+m2) += y4;
                  m++;
```



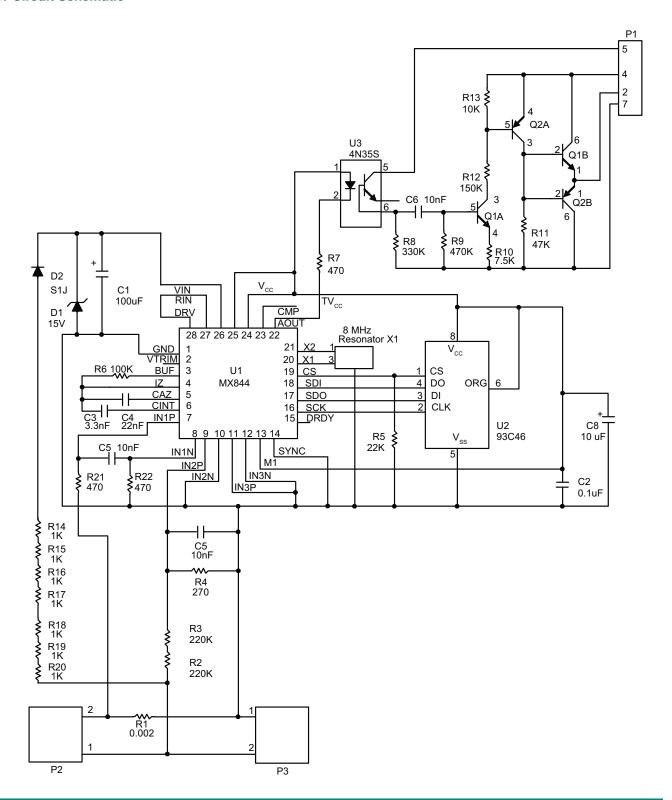
```
m + = ig1;
for(i=1;i<=n;i++)
   {
      k1 = i - 1;
      k2 = 0;
      k3 = 1 << (ig-1);
      for(k=1; k<=ig; k++)
             if((1 & k1) == 1) k2 += k3;
k3 >>= 1;
k1 >>= 1;
          }
      k5 = k2 + 1;
if ((k5-i) < 0)
          {
             y3 = *(x+i);
             (x+i) = (x+k5);

(x+k5) = y3;
             y3 = *(y+i);
*(y+i) = *(y+k5);
*(y+k5) = y3;
         }
      }
   }
```



6 Power Monitor Demo Board

6.1 Circuit Schematic

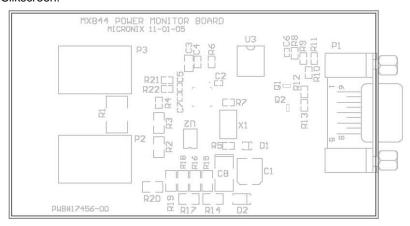


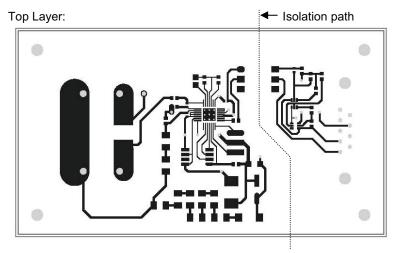


6.2 Demo Board Layout

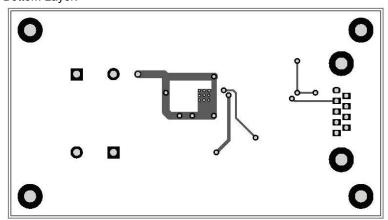
- Artwork scale approximately actual size.
- P1 is a DB-9 connector for RS-232 connection.
- P2 and P3 are screw-type terminals for AC power line connection.
- All other components are surface mount.

Silkscreen:





Bottom Layer:





6.3 Demo Board Parts List

U1	MX844	28-QFN, 5x5mm
U2	MICROCHIP 93LC46B	Serial EEPROM, 8-SOIC
U3	LiteOn 4N35S	Opto-isolator, 6-SMT
Q1	ON Semi MBT3904	Dual 2N3904, SOT-363
Q2	ON Semi MBT3906	Dual 2N3906, SOT-363
D1	ON Semi MMSZ5245B	15V, 0.5W Zener, SOD-123
D2	Fairchild S1J	600V Rectifier, SMA
X1	Abracon AWSCR-8.00MGD-T	8MHz Resonator, 7434-SMT
C1	Nichicon UWX1C101MCL1GB	100uF, 16V, 6.3x5.4 SMT
C2	Murata GRM155F51C104ZA01D	0.1uF, Y5V, 16V, 0402
C3	Murata GRM2165C1H332JA01D	3300pF, COG, 5%, 0805
	(low loss for integrator, COG acceptable	£ 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
C4	Murata GRM188R71H223MA01D	0.022uF, X7R, 20%, 0603
C5	Murata GRM155R71E103KA01D	0.01uF, X7R, 10%, 0402
C6	Murata GRM155R71E103KA01D	0.01uF, X7R, 10%, 0402
C7	Murata GRM155R71E103KA01D	0.01uF, X7R, 10%, 0402
C8	Nichicon F931A106MAA	10uF, 10V, 3.2 by 1.6, SMT
R1	Panasonic ERJ-M1WTF2M0U	0.002, 1%, 2512 (current sense type)
R2		220K, 1%, 1206
R3		220K, 1%, 1206
R4		270, 1%, 0603
R5		22K, 0603
R6		100K, 0603
R7		470, 0603
R21		470, 0603
R22		470, 0603
R8		330K, 0603
R9		470K, 0603
R10		7.5K, 0603
R11		47K, 0603
R12		150K, 0603
R13		10K, 0603
R14		1K, 1206
R15		1K, 1206
R16		1K, 1206
R17		1K, 1206
R18		1K, 1206
R19		1K, 1206
R20		1K, 1206
R20 P1	NORCOMP 182-009-212-531	DB-9 for computer serial port
P1 P2	Phoenix Contact MKDS 5/2-9.5 1714971	Suitable for AC line connection
P2 P3	Phoenix Contact MKDS 5/2-9.5 1714971 Phoenix Contact MKDS 5/2-9.5 1714971	Suitable for AC line connection
P3	FILOGILA COILCACE MADS 5/2-9.5 1/149/1	Survable for AC Time Connection



7 Manufacturing Information

7.1 Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, IPC/JEDEC J-STD-020, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
MX844R	MSL 3

7.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

7.3 Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
MX844R	260°C for 30 seconds



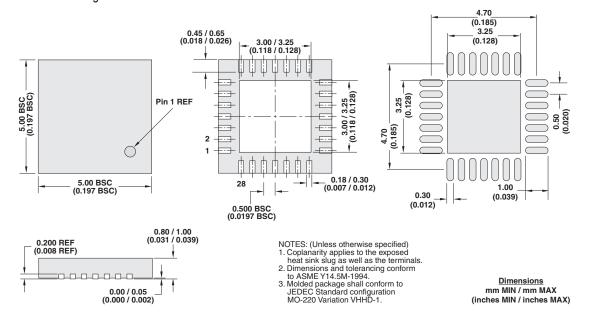




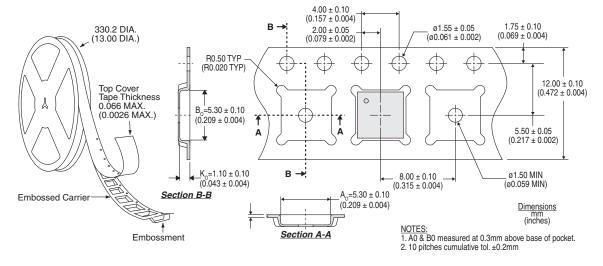


7.4 Mechanical Dimensions

7.4.1 MX844R Package



7.4.2 MX844RTR Tape & Reel



For additional information please visit www.ixysic.com

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